NSN 5962-01-165-3121

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-165-3121 **Body Length:** 1.290 inches **Body Width:** 0.600 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 53.0 milliwatts **Operating Tempurature Range:** -25.0/+85.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **End Application:** 5865-01-096-4994 radar simulator **Features Provided:** Programmable and static operation and ultraviolet erasable and 3-state output and high speed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 6.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli Fiig:

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